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ON Semiconductor®

FDB8441-F085

N-Channel PowerTrench[®] MOSFET

40V, 80A, 2.5mΩ

Features

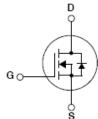
- Typ $r_{DS(on)} = 1.9m\Omega$ at $V_{GS} = 10V$, $I_D = 80A$
- Typ Q_{g(10)} = 215nC at V_{GS} = 10V
- Low Miller Charge
- Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant



Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter / Alternator
- Distributed Power Architectures and VRMs
- Primary Switch for 12V Systems





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Symbol	Parameter		Ratings	Units
V _{DS}	Drain to Source Voltage		40	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (T _C < 160°C, V _{GS} = 10V)		80	
I _D	Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, with $R_{\theta JA} = 43^{\circ}C/W$)		28	Α
	Pulsed		See Figure 4	
E _{AS}	Single Pulse Avalanche Energy (I	Note 1)	947	mJ
	Power dissipation		300	W
P _D	Derate above 25°C		2	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to 175	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	0.5	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (Note 2) 62	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient, 1in ² copper pad area	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8441	FDB8441-F085	TO-263AB	330mm	24mm	800 units

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

mbol Parameter	Test Conditions	Min	Тур	Max	Units]
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Off Characteristics

B _{VDSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{C}$	as = 0V	40	-	-	V
1	Zero Gate Voltage Drain Current	$V_{DS} = 32V$		-	-	1	
DSS	zero Gale vollage Drain Current	$V_{GS} = 0V$	$T_J = 150^{\circ}C$	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	2	2.8	4	V
		I _D = 80A, V _{GS} = 10V	-	1.9	2.5	mΩ
r _{DS(on)}	Drain to Source On Resistance	$I_D = 80A, V_{GS} = 10V, T_J = 175^{\circ}C$	-	3.3	4.3	

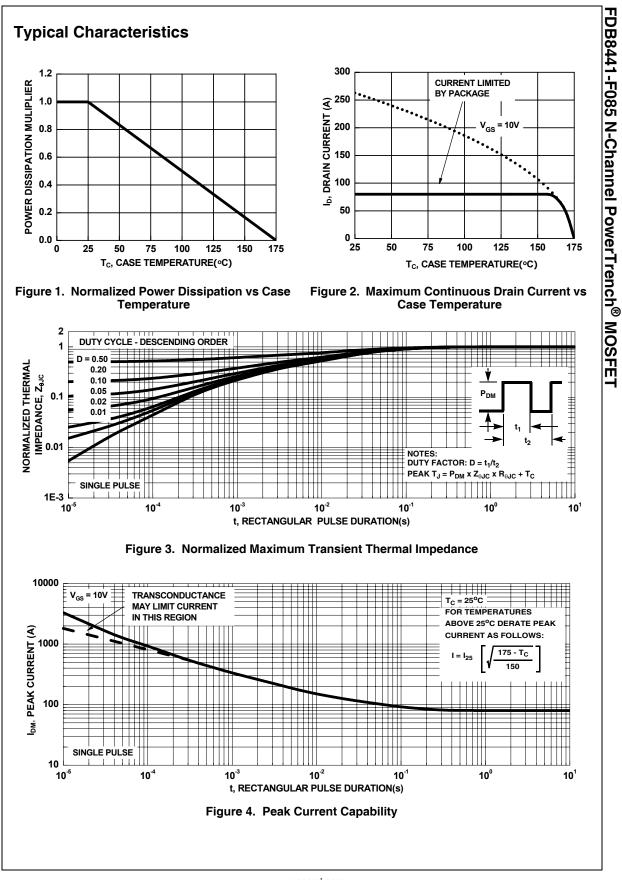
Dynamic Characteristics

Ciss	Input Capacitance		0) (-	15000	-	pF
C _{oss}	Output Capacitance	$V_{DS} = 25V, V_{GS}$	= 0V,	-	1250	-	pF
C _{rss}	Reverse Transfer Capacitance	. –		-	685	-	pF
R _G	Gate Resistance	V _{GS} = 0.5V, f = 1	MHz	-	1.1	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V		-	215	280	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{GS} = 0$ to 2V	V _{DD} = 20V	-	29	38	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 35A	-	60	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		l _g = 1mA	-	32	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		-	-	49	-	nC

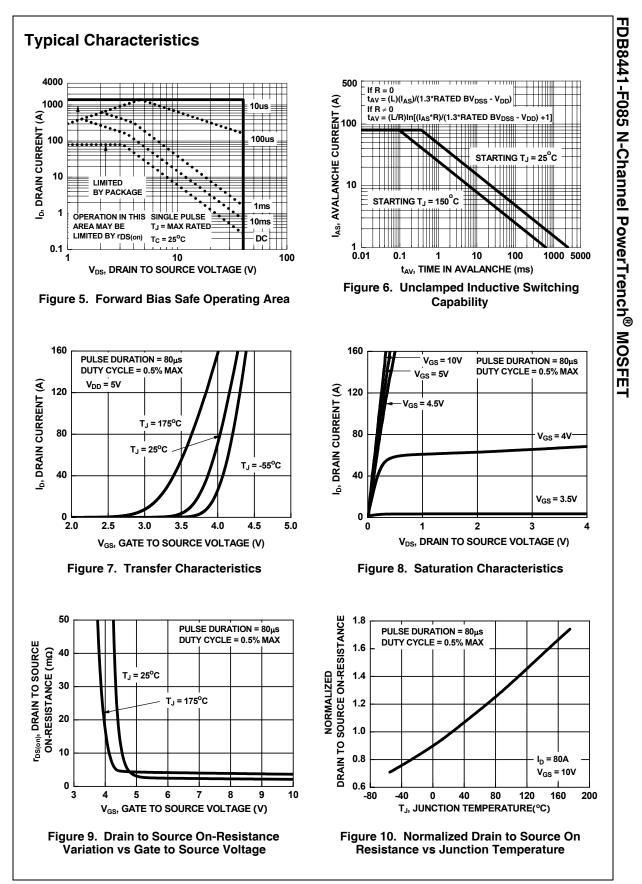
Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
witching	g Characteristics					
(on)	Turn-On Time		-	-	77	ns
d(on)	Turn-On Delay Time		-	23	-	ns
r	Turn-On Rise Time	V _{DD} = 20V, I _D = 35A	-	24	-	ns
d(off)	Turn-Off Delay Time	V_{DD} = 20V, I _D = 35A V _{GS} = 10V, R _{GS} = 1.5Ω	-	75	-	ns
f	Turn-Off Fall Time		-	17.9	-	ns
off	Turn-Off Time		-	-	147	ns

,		Source to Drain Diode Voltage	I _{SD} = 35A	-	0.8	1.25	V
	V _{SD}	Source to Drain Diode Voltage	I _{SD} = 15A	-	0.8	1.0	V
1	rr	Reverse Recovery Time	I _F = 35A, di/dt = 100A/μs	-	52	68	ns
(Q _{rr}	Reverse Recovery Charge	$I_F = 35A$, di/dt = 100A/µs	-	76	99	nC

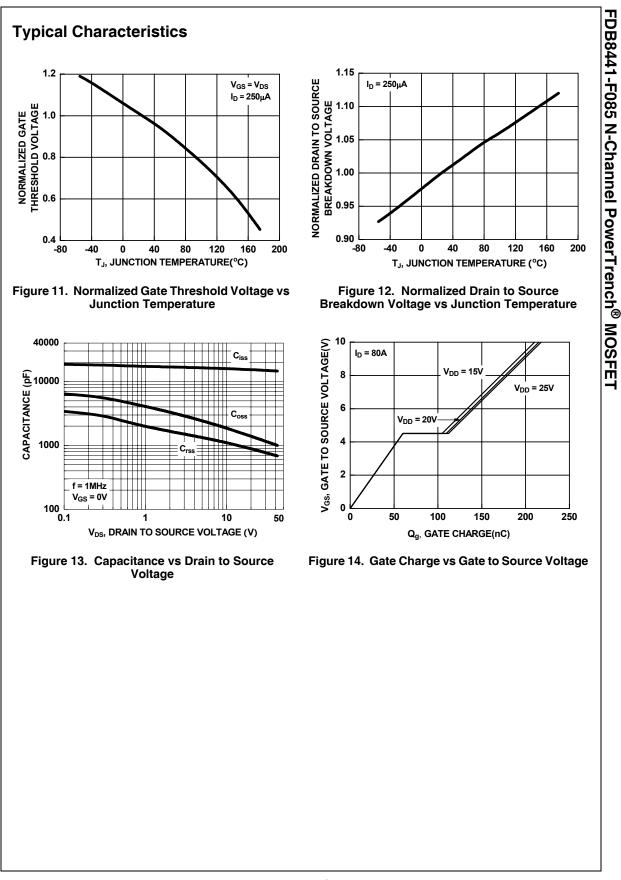
Notes: 1: Starting $T_J = 25^{\circ}C$, L = 0.46mH, I_{AS} = 64A. **2:** Pulse width = 100s.



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